NCE N-Channel Enhancement Mode Power MOSFET

Description

The NCE3085K uses advanced trench technology and design to provide excellent $R_{DS(ON)}$ with low gate charge. It can be used in a wide variety of applications.

General Features

V_{DS} =30V,I_D =85A

 $R_{DS(ON)}$ =4.2 m Ω @ V_{GS} =10V (Typ)

 $R_{DS(ON)}$ =7.0m Ω @ V_{GS} =4.5V (Typ)

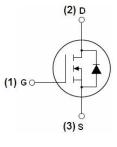
- High density cell design for ultra low Rdson
- Fully characterized avalanche voltage and current
- Good stability and uniformity with high E_{AS}
- Excellent package for good heat dissipation

Application

- Power switching application
- Hard switched and high frequency circuits
- Uninterruptible power supply

100% UIS TESTED!

100% ΔVds TESTED!



Schematic diagram



Marking and pin assignment



TO-252-2L top view

Package Marking and Ordering Information

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
NCE3085K	NCE3085K	TO-252-2L	-	-	-

Absolute Maximum Ratings (T_c=25℃unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	V _{DS}	30	V
Gate-Source Voltage	Vgs	±20	V
Drain Current-Continuous	I _D	85	А
Drain Current-Continuous(Tc=100°ℂ)	I _D (100℃)	60	Α
Pulsed Drain Current	I _{DM}	340	Α
Maximum Power Dissipation	P _D	85	W
Single pulse avalanche energy (Note 5)	E _{AS}	153	mJ
Operating Junction and Storage Temperature Range	T_{J}, T_{STG}	-55 To 175	$^{\circ}$ C

Thermal Characteristic

Thermal Resistance,Junction-to-Case ^(Note 2)	R _{θJC}	1.76	°C/W
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Electrical Characteristics (T_C=25°Cunless otherwise noted)

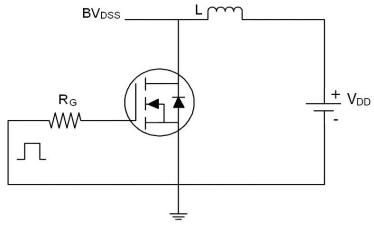
Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics			•			
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V I _D =250μA 30		-	-	V
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =30V,V _{GS} =0V	-	-	1	μΑ
Gate-Body Leakage Current	I _{GSS}	V _{GS} =±20V,V _{DS} =0V	-	-	±100	nA
On Characteristics (Note 3)						
Gate Threshold Voltage	V _{GS(th)}	$V_{DS}=V_{GS},I_{D}=250\mu A$	1.0	1.6	2.5	V
Dunin Course On Chata Besistance	Б	V _{GS} =10V, I _D =20A	+ +	4.2	4.8	mΩ
Drain-Source On-State Resistance	R _{DS(ON)}	V _{GS} =4.5V, I _D =20A		7.0	9.1	
Forward Transconductance	g FS	V _{DS} =5V,I _D =20A	-	29	-	S
Dynamic Characteristics (Note4)	·			,		
Input Capacitance	C _{lss}	\\ 45\\\\ 0\\	-	1350	-	PF
Output Capacitance	Coss	V_{DS} =15V, V_{GS} =0V, F=1.0MHz	-	220	-	PF
Reverse Transfer Capacitance	Crss	F-1.UIVIDZ	-	185	-	PF
Switching Characteristics (Note 4)			·			
Turn-on Delay Time	t _{d(on)}		-	6	-	nS
Turn-on Rise Time	t _r	V _{DD} =15V,I _D =20A	-	9	-	nS
Turn-Off Delay Time	t _{d(off)}	V_{GS} =10V, R_{G} =6 Ω	-	32	-	nS
Turn-Off Fall Time	t _f		-	8	-	nS
Total Gate Charge	Qg)/ 45)/I 00A	-	31.3		nC
Gate-Source Charge	Q _{gs}	V _{DS} =15V,I _D =20A, V _{GS} =10V	-	3.7		nC
Gate-Drain Charge	Q_{gd}	V _{GS} -1UV	-	8		nC
Drain-Source Diode Characteristics	·		·			
Diode Forward Voltage (Note 3)	V _{SD}	V _{GS} =0V,I _S =20A	-	-	1.2	V
Diode Forward Current (Note 2)	ls		-	-	85	Α
Reverse Recovery Time	t _{rr}	TJ = 25°C, IF = 20A	-	45	-	nS
Reverse Recovery Charge	Qrr	di/dt = 100A/μs ^(Note3)	-	22	-	nC
Forward Turn-On Time	t _{on}	Intrinsic turn-on time is negligible (turn-on is dominated by LS+LD)				y LS+LD)

Notes:

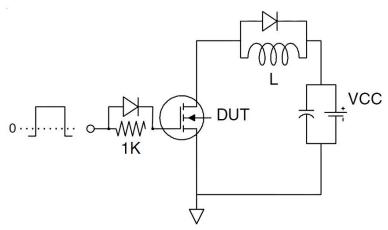
- 1. Repetitive Rating: Pulse width limited by maximum junction temperature.
- **2.** Surface Mounted on FR4 Board, $t \le 10$ sec.
- 3. Pulse Test: Pulse Width ≤ 300µs, Duty Cycle ≤ 2%.
- **4.** Guaranteed by design, not subject to production

Test circuit

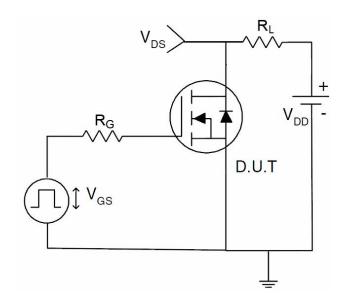
1) E_{AS} Test Circuit



2) Gate Charge Test Circuit



3) Switch Time Test Circuit





Typical Electrical and Thermal Characteristics (Curves)

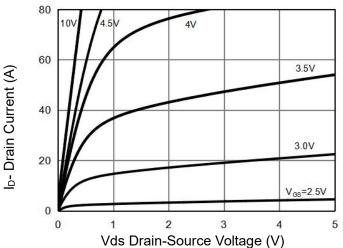


Figure 1 Output Characteristics

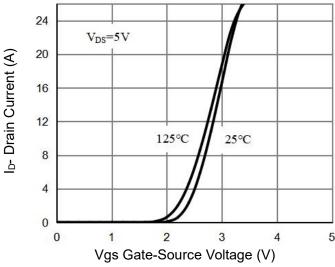


Figure 2 Transfer Characteristics

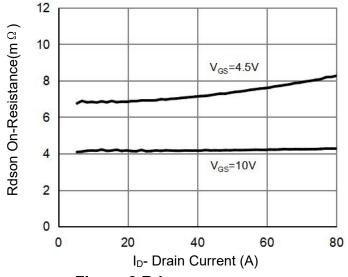


Figure 3 Rdson- Drain Current

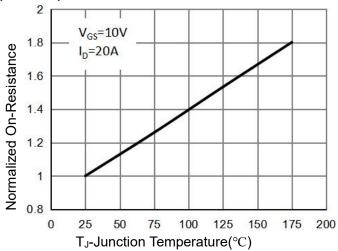


Figure 4 Rdson-JunctionTemperature

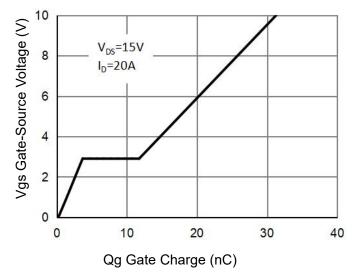


Figure 5 Gate Charge

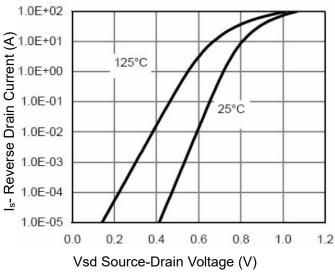


Figure 6 Source- Drain Diode Forward



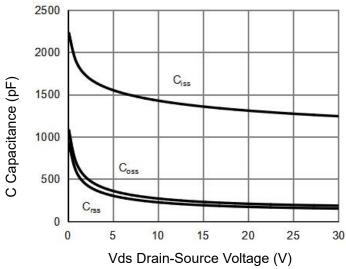


Figure 7 Capacitance vs Vds

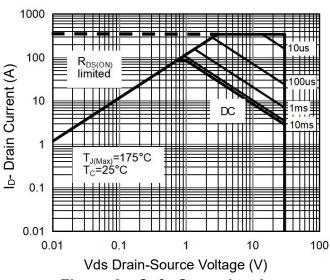


Figure 8 Safe Operation Area

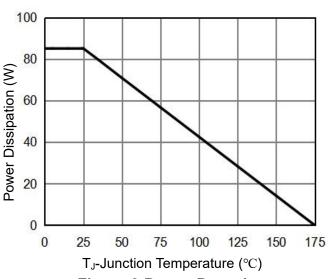


Figure 9 Power De-rating

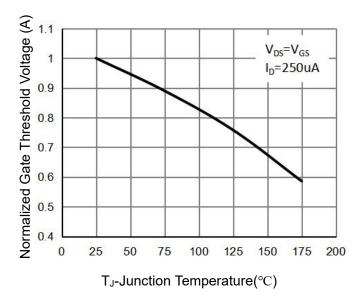


Figure 10 V_{GS(th)} vs Junction Temperature

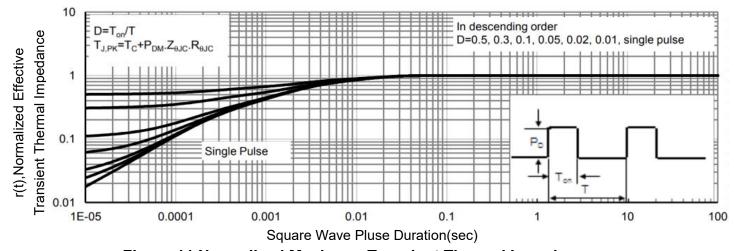
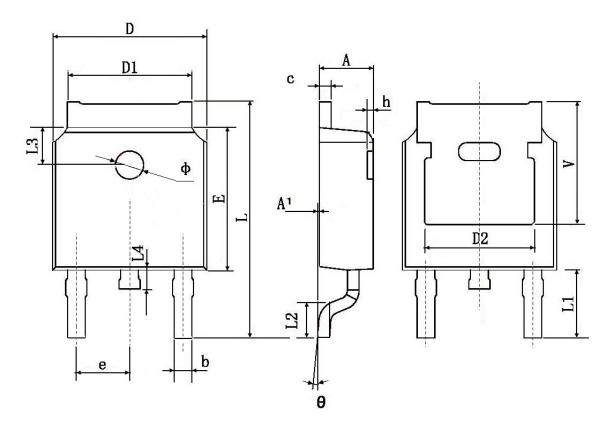


Figure 11 Normalized Maximum Transient Thermal Impedance

Wuxi NCE Power Co., Ltd Page 5 v1.0

TO-252 Package Information



Cymhal	Dimensions I	n Millimeters	Dimensions In Inches		
Symbol	Min.	Max.	Min.	Max.	
А	2.200	2.400	0.087	0.094	
A1	0.000	0.127	0.000	0.005	
b	0.660	0.860	0.026	0.034	
С	0.460	0.580	0.018	0.023	
D	6.500	6.700	0.256	0.264	
D1	5.100	5.460	0.201	0.215	
D2	4.830	TYP.	0.190 TYP.		
E	6.000	6.200	0.236	0.244	
е	2.186	2.386	0.086	0.094	
L	9.800	10.400	0.386	0.409	
L1	2.900 TYP.		0.114 TYP.		
L2	1.400	1.700	0.055	0.067	
L3	1.600 TYP.		0.063 TYP.		
L4	0.600	1.000	0.024	0.039	
Ф	1.100	1.300	0.043	0.051	
θ	0°	8°	0°	8°	
h	0.000	0.300	0.000	0.012	
V	5.350	TYP.	0.211 TYP.		

Wuxi NCE Power Co., Ltd Page 6 v1.0



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NCE3085K

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